Supporting Information

Integrated 3D self-supported Ni decorated MoO₂ nanowires as highly efficient electrocatalysts for ultra-highly stable and largecurrent-density hydrogen evolution

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Figure S1. Optical photograph of bare CC (left), Mo-Ni-O based precursors (middle),

and Ni-MoO₂-450 NWs/CC (right).



Figure S2. a) Low- and b) high-magnification SEM images of carbon cloth. c) Lowand d) high-magnification SEM images of Mo-Ni-O based precursors. e) XRD pattern of Mo-Ni-O based precursors.

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20

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40 50 2θ (degree)

60

70

80



Figure S3. a) Low- and b) high-magnification SEM images of NiMoO₄ NWs/CC. c)

XRD pattern of NiMoO₄ NWs/CC.



Figure S4. a) Low- and b) high-magnification SEM images of Ni-MoO₂-350 NWs/CC. c) Low- and d) high-magnification SEM images of Ni-MoO₂-550 NWs/CC. e) XRD pattern of Ni-MoO₂ NWs/CC annealed at different temperature. f) XRD pattern of Ni-MoO₂-550 NWs/CC with the standard crystallographic spectrum of MoNi (JCPDS 48-1745), Ni (JCPDS 04-0850) and MoO₂ (JCPDS 32-0671).



Figure S5. Exchange current densities for Ni-MoO₂-450 NWs/CC and Pt foil in 1 M KOH, which were calculated from Tafel plots by extrapolation method.





Figure S6. a) SEM image and b) XRD pattern of ETH-Ni-MoO₂-450 NWs/CC.



Figure S7. SEM images of a) CMP-MoO₂/CC, b) CMP-Ni /CC, and c) CMP-Ni-MoO₂/CC. XRD pattern of a) CMP-MoO₂/CC, b) CMP-Ni /CC, and c) CMP-Ni-MoO₂/CC.



Figure S8. Exchange current densities for Ni-MoO₂-450 NWs/CC, ETH-Ni-MoO₂-450 NWs/CC, CMP-Ni-MoO₂/CC, CMP-MoO₂/CC, and CMP-Ni/CC in 1 M KOH, which were calculated from Tafel plots by extrapolation method.



Figure S9. Electrochemically active surface area measurements. CV curves measured from 10 to 80 mV s⁻¹ in 1 M KOH of CV curves measured from 10 to 80 mV s⁻¹ of a) Ni-MoO₂-450 NWs/CC, b) ETH-Ni-MoO₂-450 NWs/CC, c) CMP-Ni-MoO₂/CC, d) CMP-MoO₂/CC, and e) CMP-Ni/CC.



Figure S10. XRD patterns of Ni-MoO₂-450 NWs/CC before and after the multicurrent-step measurement.



Figure S11. Chronoamperometry measurement at a static current density of -500 and -1,000 mA cm⁻² in 1 M KOH for more than 20 hours without *iR* correction.

Materials	Annealing temperature (°C)	Crystallinity	Chemical composition	η ₁₀ (mV)	Tafel slope (mV dec ⁻¹)
Ni-MoO ₂ -350 NWs/CC	350	Low	Ni/MoO ₂	56	42
Ni-MoO ₂ -450 NWs/CC	450	Middle	Ni/MoO ₂	40	30
Ni-MoO ₂ -550 NWs/CC	550	High	MoNi/Ni/MoO ₂	55	38

 Table S1. Summary of Ni-MoO2 NWs/CC annealed at different temperature.

Table S2. The HER activities of the Ni-MoO2-450 NWs/CC and reported catalysts in 1 M KOH.

Materials	Onset overpotential (mV)	Overpotential at 10 mA cm ⁻² (mV)	Tafel slope (mV dec ⁻¹)	Reference
Ni-MoO ₂ -450 NWs/CC	0	40	30	This work
$MoNi_4$ on MoO_2	0	15	30	1
MoS ₂ /Ni ₃ S ₂	50	110	83	2
Ni(OH) ₂ /MoS ₂	20	80	60	3
MoC-Mo ₂ C	33	120	42	4
Ni-MoC	-	123	83	5
MoP	50	130	48	6
Ni ₂ P/Ni	41	~75	50	7
N,P-doped Mo ₂ C@carbon				
nanospheres	0	50	71	8
NiMoN	50	109	95	9
Ni-WN	0	47	71	10
Co/Co ₃ O ₄	30	~90	44	11

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